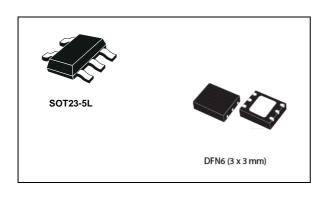


Very low drop and low noise BiCMOS 300 mA voltage regulator

Datasheet - production data



Features

- Input voltage from 2.5 V to 6 V
- Stable with low ESR ceramic capacitors
- Very low dropout voltage (150 mV typ. at 300 mA load, 0.4 mV typ. at 1 mA load)
- Very low quiescent current (85 μA typ. at no load, 200 μA typ. at 300 mA load; max.1.5 μA in OFF mode)
- Guaranteed output current up to 300 mA
- Wide range of output voltages available on request: fixed from 1.25 V to 5 V with 100 mV step
- Fast turn-on time: typ. 240 μs

- $[C_O = 2.2 \mu F, C_{BYP} = 33 \text{ nF and } I_O = 1 \text{ mA}]$
- Logic-controlled electronic shutdown
- Internal current and thermal limit
- Low output voltage noise: 30 μ V_{RMS} over 10 Hz to 100 kHz
- SVR of 55 dB at 1 kHz, 50 dB at 10 kHz
- Temperature range: 40 °C to 125 °C
- Automotive grade product available in DFN6 package, temperature range: - 40 °C to 85 °C

Description

The LDS3985 provides up to 300 mA, from 2.5 V to 6 V input voltage. It is stable with ceramic and high quality tantalum capacitor. The ultra low drop voltage, low quiescent current and low noise make it suitable for low power applications and battery-powered systems. Shutdown logic control function is available, this means that when the device is used as local regulator, it is possible to put a part of the board in standby, decreasing the total power consumption. Typical applications are mobile phones and similar battery-powered wireless systems, portable information appliances.

Table 1. Device summary

	Packages				
SOT23-5L	DFN6	DFN6 (automotive grade)	Output voltage		
LDS3985M15R	LDS3985PU15R	LDS3985PU15RY	1.5 V		
LDS3985M18R		LDS3985PU18RY	1.8 V		
LDS3985M25R		LDS3985PU25RY	2.5 V		
LDS3985M28R	LDS3985PU28R	LDS3985PU28RY	2.8 V		
LDS3985M30R		LDS3985PU30RY	3.0 V		
LDS3985M33R	LDS3985PU33R	LDS3985PU33RY	3.3 V		
LDS3985M50R			5.0 V		

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Contents LDS3985

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2	Pin configuration
3	Maximum ratings
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5	Typical performance characteristics
6	Package mechanical data 12
7	Packaging mechanical data
В	Revision history

LDS3985 Diagram

1 Diagram

ON≥1.4V

OFF≤0.4V

OFF≤0.4V

R1

Over Current & Thermal Protection

GND

Figure 1. Schematic diagram

Pin configuration LDS3985

2 Pin configuration

Figure 2. Pin connections (top view for SOT23-5L, and for DFN6)

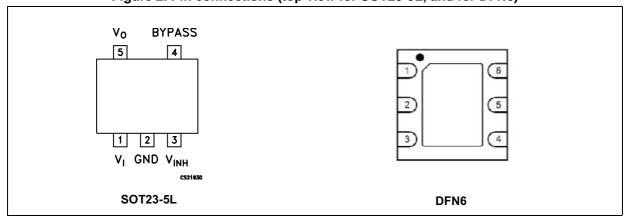


Table 2. Pin description

Pin n° for SOT23-5L	Pin n° for DFN6	Symbol	Name and function
1	1	V _I	LDO input voltage.
2	5	GND	Common ground.
3	6	V _{INH}	Inhibit input voltage: ON mode when $V_{INH} \ge 1.2$ V, OFF mode when $V_{INH} \le 0.4$ V (do not leave it floating; it is not internally pulled down/up).
4	4	Bypass	Bypass pin: an external capacitor to be connected (usually 10 nF) to minimize noise voltage
5	3	Vo	LDO output voltage
-	2	N.C.	Not connected.

LDS3985 Maximum ratings

3 Maximum ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _I	DC input voltage	-0.3 to 6 ⁽¹⁾	V
Vo	DC output voltage	-0.3 to V _I + 0.3	V
V _{INH}	Inhibit input voltage	-0.3 to V _I + 0.3	V
I _O	Output current	Internally limited	
P _D	Power dissipation	Internally limited	
T _{STG}	Storage temperature range	-65 to 150	°C
	Operating junction temperature range	-40 to 125	°C
T _{OP}	Operating junction temperature range, automotive grade version	- 40 to 85	°C

^{1.} The input pin is able to withstand non repetitive spike of $6.5\ V$ for 200 ms.

Note:

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Table 4. Thermal data

Symbol	Parameter	SOT23-5L	DFN6	Unit
R _{thJC}	Thermal resistance junction-case	81	10	°C/W
R _{thJA}	Thermal resistance junction-ambient	255	55	°C/W

Electrical characteristics LDS3985

4 Electrical characteristics

 $T_J=25~^{\circ}C,~V_I=V_{O(NOM)}+0.5~V,~C_I=1~\mu\text{F},~C_O=2.2~\mu\text{F},~C_{BYP}=33~\text{nF},~I_O=1~\text{mA},\\ V_{INH}=1.4~V,~\text{unless otherwise specified}.$

Table 5. LDS3985 electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit	
V_{I}	Operating input voltage			2.5		6	V	
Vo	Output voltage < 2.5 V	I _O = 1 mA		-50		50	m\/	
۷O	Output voltage < 2.5 v	T _J = - 40 to 125 °C		-75		75	mV	
V-	V _O Output voltage ≥ 2.5 V	I _O = 1 mA		-2		2	%	
۷O	Output voltage 2 2.5 v	T _J = - 40 to 125 °C		-3		3	V _{O(NOM)}	
ΔV_{O}	Line regulation ⁽¹⁾	$V_I = V_{O(NOM)} + 0.5 \text{ to } 6 \text{ V},$ $T_J = -40 \text{ to } 125 \text{ °C}$		-0.1		0.1	%/V	
		V _O = 4.7 to 5 V		-0.19		0.19		
ΔV _O	Load regulation	$I_O = 1 \text{ mA to } 300 \text{ mA}, V_O \le 200$ $T_J = -40 \text{ to } 125 \text{ °C}$	2.5 V		0.005	0.01	%/mA	
ΔV_{O}	Load regulation	$I_O = 1 \text{ mA to } 300 \text{ mA}, V_O \ge 2$ $T_J = -40 \text{ to } 125 \text{ °C}$	2.5 V		0.0008	0.004	%/mA	
ΔV_{O}	Output AC line regulation ⁽²⁾	$V_I = V_{O(NOM)} + 1 \text{ V, } I_O = 300 \text{ mA,}$ $t_R = t_F = 30 \mu\text{s}$			5		mV_PP	
	Quiescent current ON mode:	I _O = 0			85			
		$I_{O} = 0$, $T_{J} = -40$ to 125 °C				150		
IQ	V _{INH} = 1.4 V	I _O = 0 to 300 mA			200		μA	
·Q		$I_O = 0$ to 300 mA, $T_J = -40$ to	o 125 °C			300	μπ	
	OFF mode: V _{INH} = 0.4 V				0.003			
	OTT MOSES VINA	T _J = - 40 to 125 °C				1.5		
		I _O = 1 mA			0.4			
		$I_O = 1$ mA, $T_J = -40$ to 125 °	С			2		
V_{DROP}	Dropout voltage ⁽³⁾	I _O = 150 mA			60		mV	
· DROP	2. opear remage	$I_O = 150 \text{ mA}, T_J = -40 \text{ to } 120$	5 °C			100		
		I _O = 300 mA			150			
		$I_O = 300 \text{ mA}, T_J = -40 \text{ to } 120$	5 °C			250		
I_{SC}	Short-circuit current	$R_L = 0$	$R_L = 0$		600		mA	
		$V_{I} = V_{O(NOM)} + 0.25 V \pm$	f = 1 kHz		55			
SVR	Supply voltage rejection	$V_{RIPPLE} = 0.1 \text{ V, } I_O = 50 \text{ mA}$ For $V_{O(NOM)} < 2.5 \text{ V,}$ $V_I = 2.55 \text{ V}$	f = 10 kHz		50		dB	
	l .	l	L		l			

Table 3. ED33903 electrical characteristics (continued)						
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{O(PK)}	Peak output current	V _O ≥ V _{O(NOM)} - 5%	300	550		mA
V	Inhibit input logic low	V _I = 2.5 V to 6 V, T _{.I} = - 40 to 125 °C			0.4	V
V _{INH} Inhibit input logic high	$V_1 = 2.5 \text{ V to 6 V}, I_3 = -40 \text{ to } 125 ^{\circ}\text{C}$	1.4			V	
I _{INH}	Inhibit input current	$V_{INH} = 0.4 \text{ V}, V_{I} = 6 \text{ V}$		±1		nA
eN	Output noise voltage	B_W = 10 Hz to 100 kHz, C_O = 2.2 μ F		30		μV_{RMS}
t _{ON}	Turn-on time (4)	C _{BYP} = 33 nF		240		μs
T _{SHDN}	Thermal shutdown	(5)		160		°C
Co	Output capacitor	Capacitance	2.2		22	μF
	Output capacitor	ESR	5		5000	mΩ

Table 5. LDS3985 electrical characteristics (continued)

- 1. For $V_{O(NOM)}$ < 2 V, V_I = 2.5 V.
- 2. For $V_{O(NOM)} = 1.25 \text{ V}$, $V_I = 2.5 \text{ V}$.
- 3. Dropout voltage is the input-to-output voltage difference at which the output voltage is 100 mV below its nominal value. This specification does not apply to input voltages below 2.5 V.
- 4. Turn-on time is time measured between the enable input just exceeding V_{INH} high value and the output voltage just reaching 95% of its nominal value.
- 5. Typical thermal protection hysteresis is 20 °C.

Table 6. LDS3985 (automotive grade) electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
VI	Operating input voltage		2.5		6	V
V	Output voltage < 2.5 V	I _O = 1 mA	-50		50	mV
Vo	Output Voltage < 2.5 V	T _J = - 40 to 85 °C	-75		75	IIIV
.,	0	I _O = 1 mA	-2		2	%
Vo	Output voltage ≥ 2.5 V	T _J = - 40 to 85 °C	-3		3	V _{O(NO} M)
ΔV _O	ΔV _O Line regulation ⁽¹⁾	$V_I = V_{O(NOM)} + 0.5 \text{ to 6 V},$ $T_J = -40 \text{ to } 85 ^{\circ}\text{C}$	-0.1		0.1	%/V
		$V_{O} = 4.7 \text{ to 5 V}$	-0.19		0.19	
ΔV _O	Load regulation	I_O = 1 mA to 300 mA, V_O ≤ 2.5 V T_J = - 40 to 85 °C		0.005	0.01	%/mA
ΔV _O	Load regulation	I_O = 1 mA to 300 mA, V_O \geq 2.5 V T_J = - 40 to 85 °C		0.0008	0.004	%/mA
ΔV _O	Output AC line regulation ⁽²⁾	$V_I = V_{O(NOM)} + 1 \text{ V, } I_O = 300 \text{ mA,}$ $t_R = t_F = 30 \mu\text{s}$		5		${\rm mV}_{\rm PP}$

Electrical characteristics LDS3985

Table 6. LDS3985 (automotive grade) electrical characteristics (continued)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit	
		I _O = 0			85			
	Quiescent current ON $I_O = 0$, $T_J = -40$ to 85					150		
	mode: V _{INH} = 1.4 V	I _O = 0 to 300 mA			200		^	
IQ	Iq	$I_{O} = 0$ to 300 mA, $T_{J} = -40$ to	o 85 °C			300	μΑ	
					0.003			
	OFF mode: V _{INH} = 0.4 V	T _J = - 40 to 85 °C				1.5		
		I _O = 1 mA			0.4			
	I_{O} = 1 mA, T_{J} = -40 to 85 °C				2			
	Drangust valtage (3)	I _O = 150 mA			60		\	
V _{DROP} Dropout voltage ⁽³⁾	Dropout voltage(*)	I _O = 150 mA, T _J = - 40 to 85 °C				100	mV	
		I _O = 300 mA			150			
		I _O = 300 mA, T _J = - 40 to 85 °C				250		
I _{SC}	Short-circuit current	R _L = 0	R _L = 0		600		mA	
		. ()	f = 1 kHz		55			
SVR	Supply voltage rejection	$\begin{split} &V_{RIPPLE} = 0.1 \text{ V, } I_O = 50 \text{ mA} \\ &\text{For } V_{O(NOM)} < 2.5 \text{ V,} \\ &V_I = 2.55 \text{ V} \end{split}$	f = 10 kHz		50		dB	
I _{O(PK)}	Peak output current	$V_O \ge V_{O(NOM)}$ - 5%		300	550		mA	
V	Inhibit input logic low	$V_{\rm I} = 2.5 \text{ V to 6 V, } T_{\rm J} = -40 \text{ to}$	0F °C			0.4	V	
V _{INH}	Inhibit input logic high	$-\frac{1}{2}$ $\sqrt{1}$ = 2.5 $\sqrt{10.6}$ $\sqrt{1}$ $\sqrt{1}$ = -40 $\sqrt{10}$	165 C	1.4			- V	
I _{INH}	Inhibit input current	V _{INH} = 0.4 V, V _I = 6 V			±1		nA	
eN	Output noise voltage	$B_W = 10 \text{ Hz to } 100 \text{ kHz}, C_O = 2.2 \mu\text{F}$			30		μV_{RMS}	
t _{ON}	Turn-on time (4)	C _{BYP} = 33 nF			240		μs	
T _{SHDN}	Thermal shutdown	(5)			160		°C	
C	Output capacitor	Capacitance		2.2		22	μF	
Co	Ουτραί σαρασίτοι	ESR		5		5000	mΩ	

^{1.} For $V_{O(NOM)} < 2 \text{ V}$, $V_I = 2.5 \text{ V}$.

^{2.} For $V_{O(NOM)} = 1.25 \text{ V}$, $V_I = 2.5 \text{ V}$.

^{3.} Dropout voltage is the input-to-output voltage difference at which the output voltage is 100 mV below its nominal value. This specification does not apply to input voltages below 2.5 V.

^{4.} Turn-on time is time measured between the enable input just exceeding V_{INH} high value and the output voltage just reaching 95% of its nominal value.

^{5.} Typical thermal protection hysteresis is 20 °C.

5 Typical performance characteristics

 T_J = 25 °C, V_I = $V_{O(NOM)}$ + 0.5 V, C_I = 1 $\mu F,\,C_O$ = 2.2 $\mu F,\,C_{BYP}$ = 33 nF, I_O = 1 mA, V_{INH} = 1.4 V, unless otherwise specified.

Figure 3. Output voltage vs. temperature $V_0 = 1.35 \text{ V}$

V₀ (V) 1.39 1.38 1.37 1.36 1.35 1.34 1.33 $V_1 = 2.5V$ 1.32 $I_0 = 1 \, \text{mA}$ 1.31 1.30 L -50 50 100 T_J(°C)

Figure 4. Output voltage vs. temperature $V_0 = 2.8 \text{ V}$

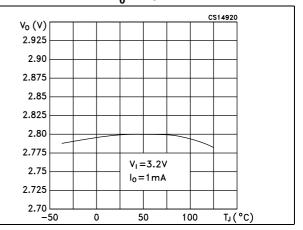
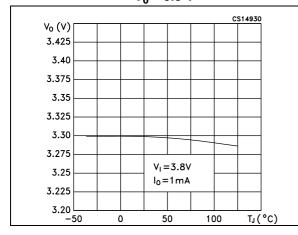


Figure 5. Output voltage vs. temperature $V_0 = 3.3 \text{ V}$

Figure 6. Inhibit voltage vs. temperature $V_0 = 1.35 \text{ V}$



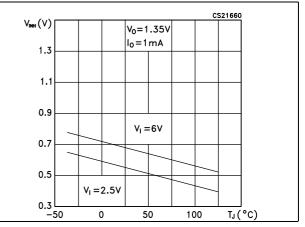


Figure 7. Inhibit voltage vs. temperature $(V_O = 3.3 V)$

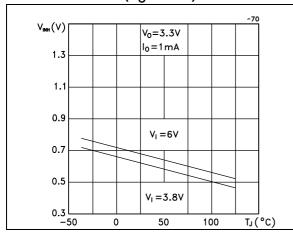


Figure 8. Line regulation vs. temperature $(V_I = 2.5 \text{ V to } 6 \text{ V})$

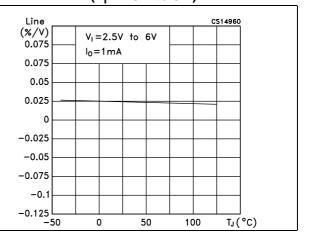
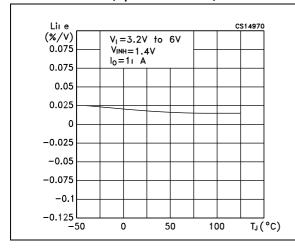


Figure 9. Line regulation vs. temperature $(V_I = 3.2 \text{ V to } 6 \text{ V})$

Figure 10. Line regulation vs. temperature (V_I = 3.8 V to 6 V)



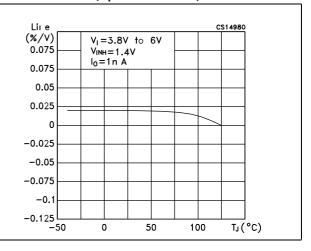
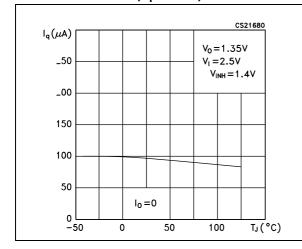
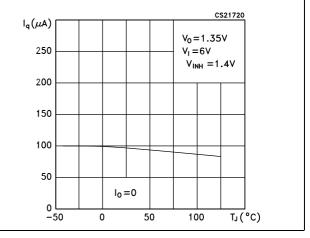


Figure 11. Quiescent current vs. temperature $(V_1 = 2.5 \text{ V})$

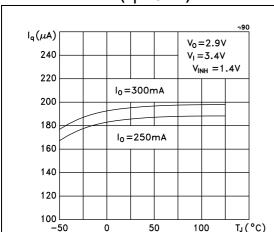
Figure 12. Quiescent current vs. temperature $(V_1 = 6 V)$





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Figure 13. Quiescent current vs. temperature $(V_1 = 3.4 V)$



0

Figure 14. Supply voltage rejection vs. frequency

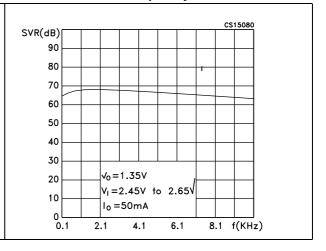


Figure 15. Dropout voltage vs. temperature

50

100

T_J (°C)

CS21700 $V_{DROP}(V)$ $V_{INH} = V_I$ 0.18 0.16 0.14 I₀=300mA 0.12 0.1 0.08 0.06 0.04 $I_0 = 150 \text{mA}$ 0.02 -50 0 50 100 T_J (°C)

Figure 16. Dropout voltage vs. output current

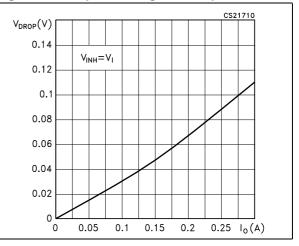
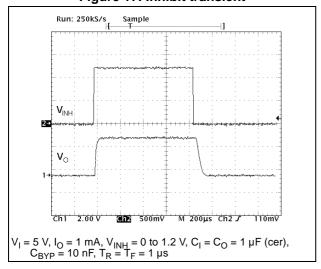


Figure 17. Inhibit transient





6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

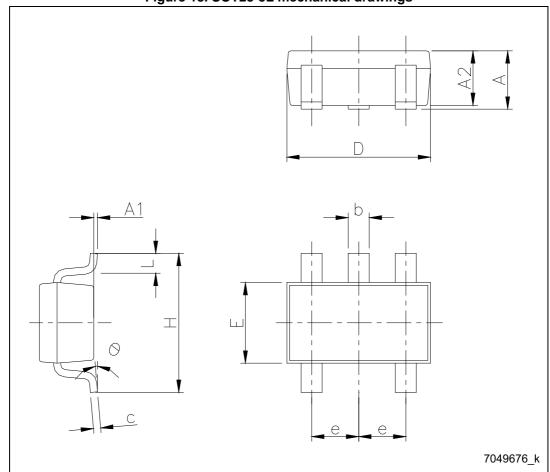
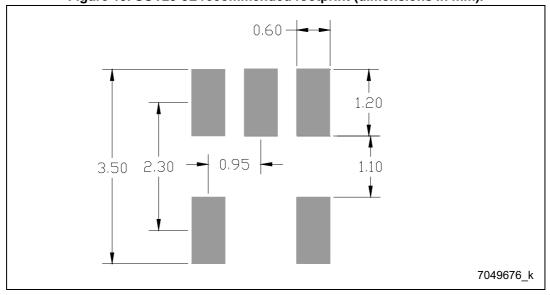


Figure 18. SOT23-5L mechanical drawings

Table 7. SOT23-5L mechanical data

Dim.	mm				
Dim.	Min.	Тур.	Max.		
А	0.90		1.45		
A1	0		0.15		
A2	0.90		1.30		
b	0.30		0.50		
С	2.09		0.20		
D		2.95			
E		1.60			
е		0.95			
Н		2.80			
L	0.30		0.60		
θ	0		8		

Figure 19. SOT23-5L recommended footprint (dimensions in mm).



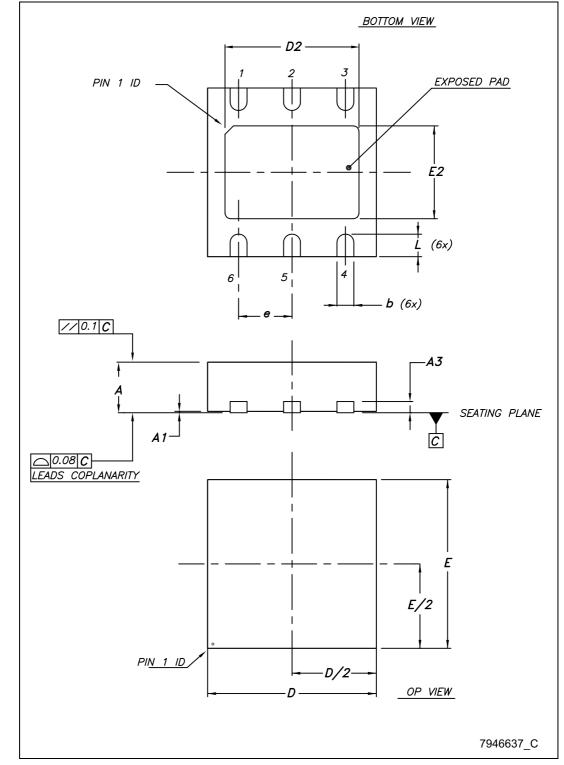


Figure 20. DFN6 (3 x 3 mm) drawings

Table 8. DFN6 (3 x 3 mm) mechanical data

Dim.	mm				
Dilli.	Min.	Тур.	Max.		
А	0.80		1		
A1	0	0.02	0.05		
А3		0.20			
b	0.23		0.45		
D	2.90	3	3.10		
D2	2.23		2.50		
E	2.90	3	3.10		
E2	1.50		1.75		
		0.95			
L	0.30	0.40	0.50		



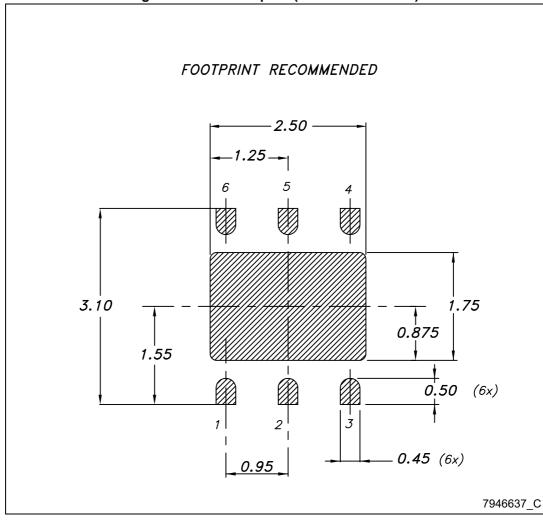


Figure 21. DFN6 footprint (dimensions in mm)

7 Packaging mechanical data

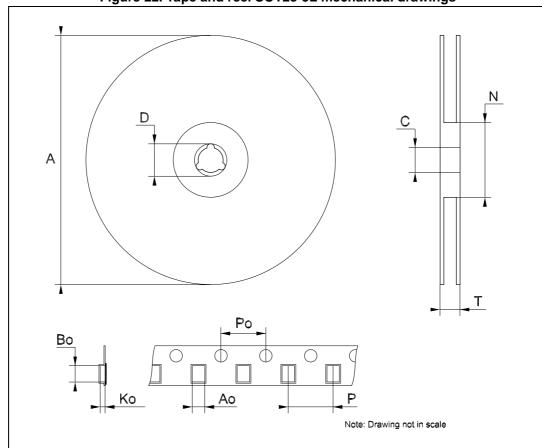


Figure 22. Tape and reel SOT23-5L mechanical drawings

Table 9. Tape and reel SOT23-5L mechanical data

Dim.	mm				
Dilli.	Min.	Тур.	Max.		
Α			180		
С	12.8	13.0	13.2		
D	20.2				
N	60				
Т			14.4		
Ao	3.13	3.23	3.33		
Во	3.07	3.17	3.27		
Ko	1.27	1.37	1.47		
Po	3.9	4.0	4.1		
Р	3.9	4.0	4.1		

KO ø1.5 8 ±0.10 0.30 AO R 0.3 max ВО +0.10 ø1.5 ±0.05 COVER ±0.10 * - *10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ±0.20 7875978_N

Figure 23. Tape for DFN6

#0.5 #1.3 #3.30 (13")

18.4 Mc (Measured at hu
)

(Measured at hub) 12.4

7875978_N

Figure 24. Reel for DFN6

Table 10. DFN6 tape and reel mechanical data

Dim.	mm		
	Min.	Тур.	Max.
A0	3.20	3.30	3.40
В0	3.20	3.30	3.40
K0	1	1.10	1.20

Revision history LDS3985

8 Revision history

Table 11. Document revision history

Date	Revision	Changes	
02-Dec-2004	1	First release.	
10-Apr-2007	2	Added: new package TSOT23-5L.	
16-May-2007	3	Added: new mechanical data DFN6D and order codes updated.	
06-Sep-2007	4	Added: Table 1 in cover page.	
11-Jun-2008	5	Modified: Table 10 on page 20.	
11-Jul-2009	6	Modified: Table 10 on page 20.	
29-Jul-2010	7	Modified: Table 1 on page 1 and Table 10 on page 20.	
24-Oct-2013	8	Modified the Title and the Features in cover page. Deleted Table1: Device summary. Updated Table 10: Order codes and Section 6: Package mechanical data. Added Table 6: LDS3985 (automotive grade) electrical characteristics and Section 7: Packaging mechanical data. Minor text changes.	
28-Feb-2014	9	Part number LDS3985xx changed to LDS3985. Updated the features, the description and <i>Table 1: Device summary</i> in cover page. Updated <i>Table 5: LDS3985 electrical characteristics</i> , <i>Table 6: LDS3985 (automotive grade) electrical characteristics</i> , <i>Section 5: Typical performance characteristics</i> . Minor text changes.	

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